



InGaAs APD FOR OTDR

Features

- Small Dark Current: $I_D = 2 \text{ nA}$
 - Small Terminal Capacitance: $C_T = 0.35 \text{ pF}$ at 0.9 VBR
 - High Quantum Efficiency:
 $\eta = 90\%$ at $\lambda = 1310 \text{ nm}$, $M = 1$ $\eta = 77\%$ at $\lambda = 1550 \text{ nm}$, $M = 1$
 - High Speed Response : $f_c = 2.5 \text{ GHz}$ at $M = 10$
 - Detecting Area Size: $50 \mu\text{m}$
- Coaxial Module With Single Mode Fiber (SM-9/125)



Applications

OTDR System/Other Sensing Probe

Absolute Maximum Ratings

Parameter	Symbol	Min.	Typ.	Max.	Unit
Forward Current	IF			10	mA
Reverse Current	IR			0.5	mA
Operating Case Temp.	TC	-40		85	°C
Storage Temperature	TSTG	-40		85	°C
Lead Soldering Temp.	TSOL			260(10s)	°C
Relative Humidity	RH	0		85	%

Optical & Electrical Characteristics

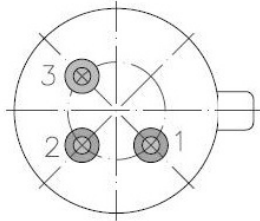
Parameter	Symbol	Min.	Typ.	Max.	Unit	Notes
Reverse Breakdown Voltage	VBR	40	45	55	V	$I_D = 100 \mu\text{A}$
Temperature Coefficient of Reverse Breakdown Voltage	δ		0.2		%/°C	
Dark Current	I_D		5	25	nA	$V_R = VBR \times 0.9$
Multiplied Dark Current	IDM		1	3	nA	$M = 2$ to 10
Terminal Capacitance	C_t		0.35		pF	$V_R = VBR \times 0.9$, $f = 1 \text{ MHz}$
Cut-off Frequency	f_c	2.5			GHz	$M = 10$
Quantum Efficiency	η	76	90		%	$\lambda = 1310 \text{ nm}$, $M = 1$
		65	77			$\lambda = 1550 \text{ nm}$, $M = 1$
Responsivity	S	0.85	0.90		A/W	$\lambda = 1310 \text{ nm}$, $M = 1$
		0.90	0.95			$\lambda = 1550 \text{ nm}$, $M = 1$
Excess Noise Factor	X		0.7		-	$\lambda = 1310 \text{ nm}$, $I_{PO} = 1.0 \mu\text{W}$, $M = 10$, $f = 35 \text{ MHz}$, $B = 1 \text{ MHz}$
	F		5			$\lambda = 1550 \text{ nm}$, $I_{PO} = 1.0 \mu\text{W}$, $M = 10$, $f = 35 \text{ MHz}$, $B = 1 \text{ MHz}$
Optical Return Loss	ORL	30	40		dB	SMF

Pin Assignment

Address: 5-floor, Block B Creative Building, Shaojia Tsui, Wenzhi St., Hongshan District, Wuhan, City, Hubei, P.R. China
430074

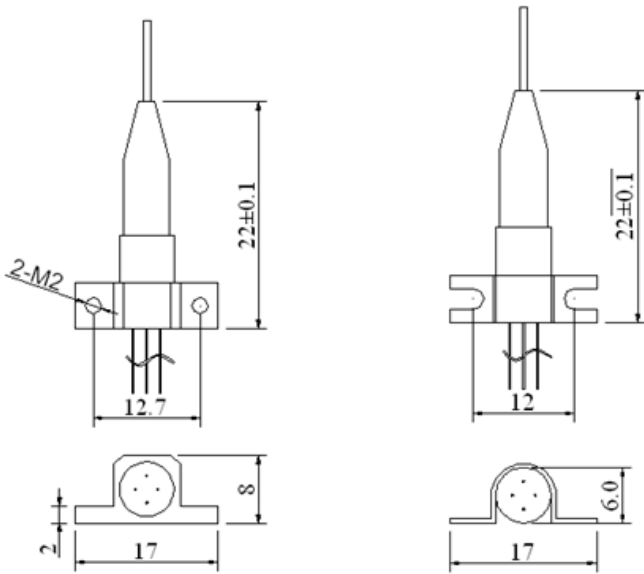


PIN:

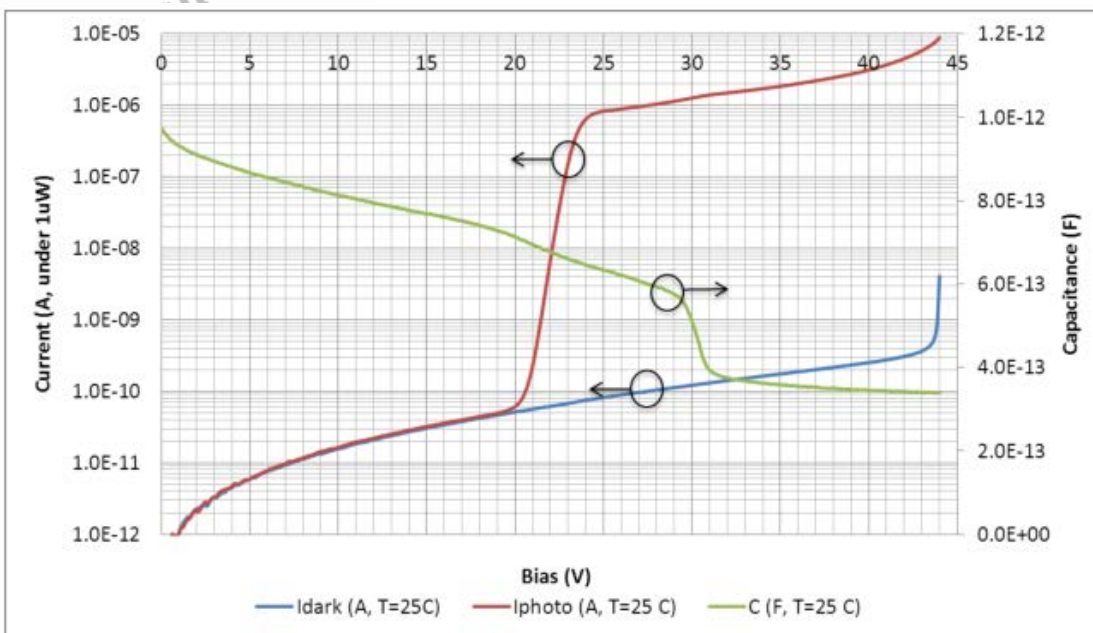


Type A:
 【1】 PD +
 【2】 PD -
 【3】 CASE

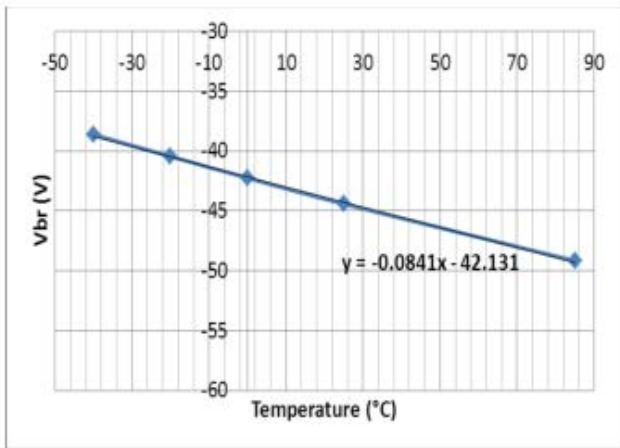
Drawing



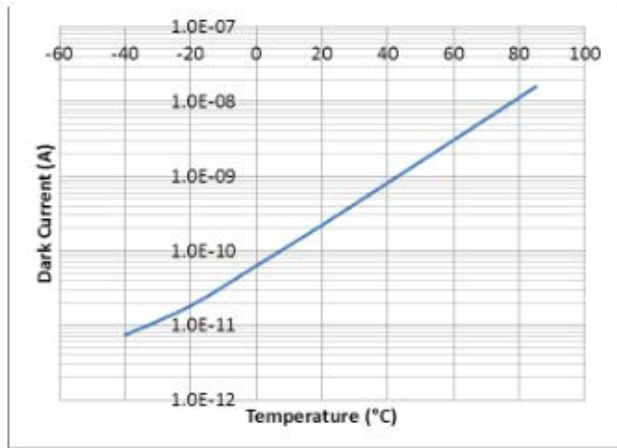
Typical Performance at 25°C



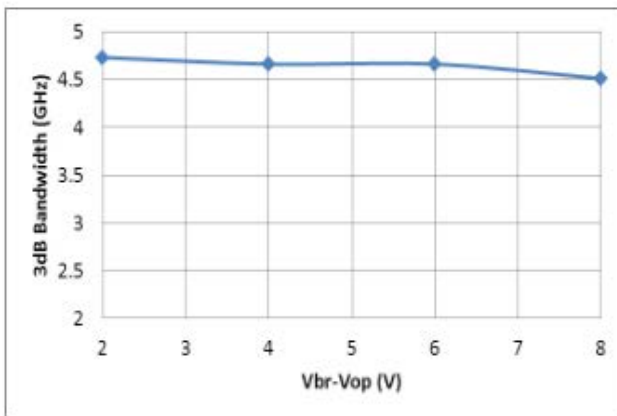
Dark Current, Photo Current, Capacitance vs. Voltage at 25°C



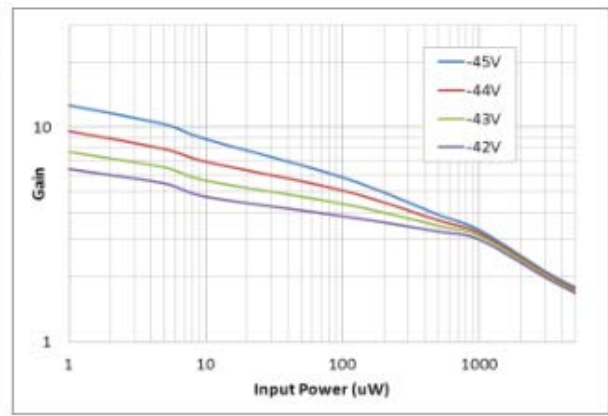
Breakdown Voltage vs. Temperature



Dark Current (at V_{br}-3V) vs. Temperature



Bandwidth vs. Operating Voltage (25°C)



Gain vs. Input Power (25°C)

Order Information

MAP-3XXX

M	AP	-3	X	X	X
Mode	Product Type	Bandwidth	Connector	Fiber Type	Pigtail Length
		3: 3Gb/s	1: FC/APC 2: FC/PC 3: SC/APC 4: SC/PC 5: LC/PC 6: LC/APC W: Without	S9: 9/125/900um S2: 9/125/250um M5: 50/125/900um M6: 62.5/125/900um	05: 0.5M 10: 1.0M

Additional requirements can be settled through friendly negotiation.

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